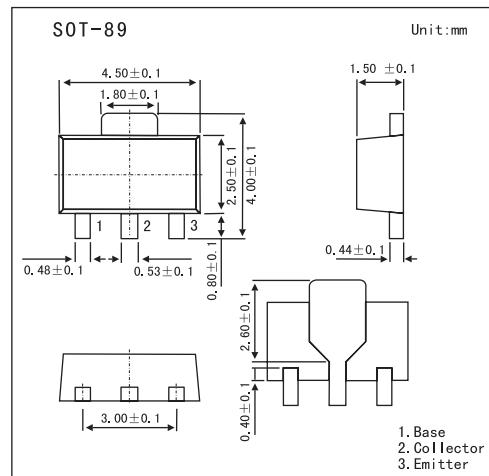


PXT2907A

■ Features

- High current (max. 600 mA)
- Low voltage (max. 60 V).



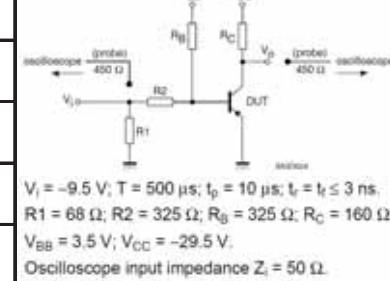
■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-60	V
Collector-emitter voltage	V _{C EO}	-60	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	I _C	-600	mA
Peak collector current	I _{CM}	-800	mA
Peak base current	I _{BM}	-200	mA
Total power dissipation	P _{tot}	1.3	W
Storage temperature	T _{stg}	-65 to +150	°C
Junction temperature	T _j	150	°C
Operating ambient temperature	T _{amb}	-65 to +150	°C
Thermal resistance from junction to ambient	R _{th(j-a)}	97	K/W
Thermal resistance from junction to soldering point	R _{th(j-s)}	17	K/W

PXT2907A

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I _{CBO}	I _E = 0; V _{CB} = -50 V			-10	nA
		I _E = 0; V _{CB} = -50 V; T _j = 125 °C			-10	µA
Emitter cutoff current	I _{EBO}	I _C = 0; V _{EB} = -5 V			-50	nA
DC current gain	h _{FE}	I _C = -0.1 mA; V _{CE} = -1 V	75			
		I _C = -1 mA; V _{CE} = -1 V	100			
		I _C = -10 mA; V _{CE} = -1 V	100			
		V _{CE} = -2 V, I _C = -150 mA	100		300	
		I _C = -500 mA; V _{CE} = -2 V	50			
collector-emitter saturation voltage	V _{CESat}	I _C = -150 mA; I _B = -15 mA			-400	mV
		I _C = -500 mA; I _B = -50 mA			-1.6	V
base-emitter saturation voltage	V _{BESat}	I _C = -150 mA; I _B = -15 mA			-1.3	V
		I _C = -500 mA; I _B = -50 mA			-2.6	V
Collector capacitance	C _c	I _E = i _E = 0; V _{CB} = -10 V; f = 1 MHz			8	pF
Emitter capacitance	C _e	I _C = i _C = 0; V _{EB} = -500 mV; f = 1 MHz			35	pF
Transition frequency	f _T	I _C = -20 mA; V _{CE} = -10 V; f = 100 MHz	200			MHz
Turn-on time	t _{on}	I _{Con} = -150 mA; I _{Bon} = -15 mA; I _{Boff} = 15 mA			40	ns
Delay time	t _d				12	ns
Rise time	t _r				30	ns
Turn-off time	t _{off}				365	ns
Storage time	t _s	V _i = -9.5 V; T = 500 µs; t _p = 10 µs; t _r = t _f ≤ 3 ns; R ₁ = 68 Ω; R ₂ = 325 Ω; R _B = 325 Ω; R _C = 160 Ω; V _{BB} = 3.5 V; V _{CC} = -29.5 V; Oscilloscope input impedance Z _i = 50 Ω.			300	ns
Fall time	t _f				65	ns



■ Marking

Marking	p2F
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